



# GaAs High Isolation Switch DC - 3.0 GHz

SW-439 V3

#### **Features**

- Low Power Consumption: < 15 μA @ +2.5V
- High Isolation: 50 dB Typical @ 2 GHz
- Low Insertion Loss: 0.7 dB @ 2 GHz
- Positive 2.5 to 5 V Control
- Low Cost Plastic MSOP-10 Package

## **Description**

M/A-COM's SW-439 is a GaAs MMIC SPDT switch in a low cost MSOP-10 surface mount plastic package. This part is ideal for high isolation, broadband switching requirements. Typical applications include synthesizer switching, transmit/receive switching, switch matrices and filter banks in systems such as radio and cellular equipment, PCM, GPS, and fiber optic modules.

The SW-439 is fabricated as a monolithic GaAs MMIC using a 0.5 micron PHEMT process. The process features full passivation.

## **Ordering Information**

Part Number	Package
SW-439	Bulk Packaging
SW-439TR	1000 piece reel
SW-439SMB	Sample Board

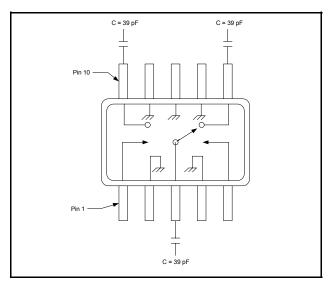
Note: Reference Application Note M513 for reel size information.

# **Absolute Maximum Ratings <sup>1,2</sup>**

Parameter	Absolute Maximum		
Input Power	+30 dBm		
Operating Voltage	+8.5 Volts		
Operating Temperature	-40°C to +85°C		
Storage Temperature	-65°C to +150°C		

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM does not recommend sustained operation near these survivability limits.

## Functional Schematic <sup>3</sup>



3. For improved performance at frequencies below 500 MHz, use larger value capacitors.

## **Pin Configuration**

Pin No.	Function	Pin No.	Function
1	Control 1	6	RF Port 2
2	Ground	7	Ground
3	RF Input	8	Ground
4	Ground	9	Ground
5	Control 2	10	RF Port 1

## Truth Table 4,5

Control V1	Control V2	RFC - RF1	RFC - RF2
0	1	Off	On
1	0	On	Off

- External DC blocking capacitors are required on all RF ports
- 5. "0" =  $0 \pm 0.2$  Vdc, "1" =  $\pm 2.5$  to  $\pm 5$  Vdc

information.

<sup>•</sup> North America Tel: 800.366.2266 / Fax: 978.366.2266

<sup>•</sup> Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





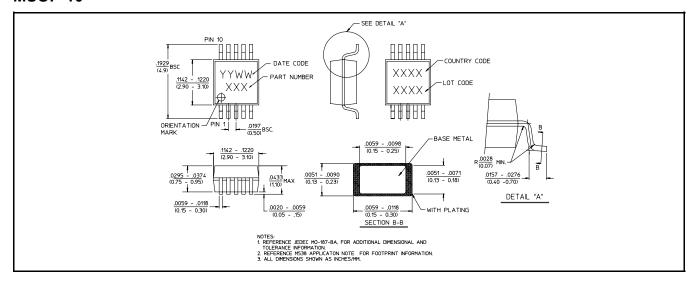
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### Electrical Specifications: $T_A = 25^{\circ}C$ , $V_C = 0 / 3 V$ , $Z_0 = 50\Omega$

Parameter	Test Conditions	Units	Min	Тур	Max
Insertion Loss	DC - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz	dB dB dB		0.55 0.65 0.80	0.65 0.75 0.90
Isolation	DC - 2.0 GHz 2.0 - 3.0 GHz	dB dB	45 31	47 33	_
VSWR	0.25 - 3.0 GHz	Ratio	_	1.2:1	1.3:1
P1dB	500 MHz - 2.0 GHz, V <sub>C</sub> = 2.5 V	dBm	_	20	_
P1dB	500 MHz - 2.0 GHz, V <sub>C</sub> = 5 V	dBm	_	28	_
IP2	2 Tone, 900 MHz, 5 MHz Spacing, $V_C$ = 3 V	dBm	_	85	_
IP3	2 Tone, 900 MHz, 5 MHz Spacing, $V_C$ = 3 V	dBm	_	50	_
Ton, Toff	50% Control to 90% RF, 50% Control to 10% RF	nS	_	20	_
Trise, Tfall	10% to 90% RF, 90% to 10% RF	nS	_	10	_
Transients	In-band	mV	_	15	_
Control Current	V <sub>C</sub>   = 2.5 V	μΑ	_	5	15

### MSOP-10



# **Handling Procedures**

Please observe the following precautions to avoid damage:

# Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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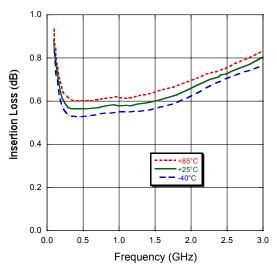


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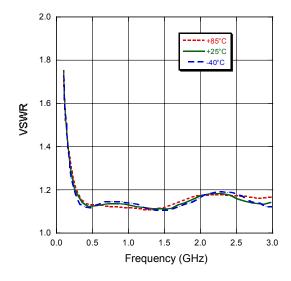
SW-439

## **Typical Performance Curves**

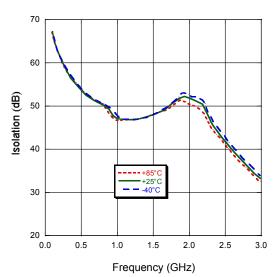
#### Insertion Loss



### **VSWR**



#### Isolation



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